

Aman BAUNTHIYAL

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PROFILE

Physicist and surface scientist nearing PhD completion in next-generation non-volatile resistive switching technology. Expertise in UHV systems, electron & X-ray microscopy, and growth of organic/inorganic materials via RF sputtering, MBE, and coating techniques, with focus on NVM applications. Proven record of leading research to publication (3 peer-reviewed papers, multiple international presentations and invited talks). Seeking a postdoc position in semiconductor devices and materials innovation.

PERSONAL INFORMATION

DOB: 01.04.1998

Citizenship: Indian

Family: Single

Languages: German (B1), English (Fluent), Hindi (Native)

EXPERTISE

- **Experimental Techniques & Instrumentation:**
 - UHV systems operation & maintenance
 - PVD (Epitaxy, RF Sputtering)
 - Microscopy and spectroscopy (e.g., STM, XPS, AFM)
- **Materials & Processes:**
 - Wide bandgap oxides & polymers growth
 - Nanomaterial fabrication
 - Semiconductor device processing
- **Scientific Domains:**
 - Surface physics
 - Semiconductor physics
 - Resistive switching technology

EXPERIENCE

RESEARCH ASSOCIATE at *University of Bremen (Germany)*.

2019.10–pres.

- ◇ Led a research on oxide-based non-volatile memory (NVM), focusing on both thin-film growth and electrical characterization.
- ◇ Managed and maintained multi-chamber ultra-high vacuum (UHV) systems including microscopy and deposition techniques like MBE and RF sputtering.
- ◇ Performed interdisciplinary collaboration with national and international working groups to advance research objectives.
- ◇ supervised bachelor's and master's projects.

EDUCATION

DOCTORATE IN PHYSICS *University of Bremen, Germany.* **2019–pres.**
Supervisor: Prof. Dr. Jens Falta

◇ **Thesis title: Growth and Electrical Characterization of RF Sputtered Ga₂O₃ on Ru(0001) for NVM Technology.**

- ◇ Developed and optimized RF sputtering processes for growing crystalline Ga₂O₃ films for ReRAM devices.
- ◇ Presented research findings through scientific publications and at various international conferences.

MASTERS OF SCIENCE IN PHYSICS. *Indian Institute of Technology Jodhpur, India* (Grade: 8.89/10, German grade: 1.55) **2017–2019**

Supervisor: Dr. Satyajit Sahu

◇ **Thesis title: Organic memory devices: a study on the impact of device fabrication processes and oxide surface morphology.**

- ◇ Growth study of organic films using spin coater and dip coating.
- ◇ Electrical characterization using two-probe station and STM of organic films for ReRAMs.

BACHELORS OF SCIENCE IN PHYSICS. *University of Delhi, India* (Grade: 8.89/10, German grade: 1.50) **2014–2017**

◇ Project title: *Investigation of polymer-based electrode for all-solid-state high-performance super capacitor.*

PUBLICATION

◇ **Baunthiyal, Aman**, et al. "Structural evolution and nucleation dynamics of RF sputtered Ga₂O₃ films on Ru (0001): The impact of deposition temperature and Ru surface morphology." *APL Materials* 13.4 (2025).

DOI: [10.1063/5.0270431](https://doi.org/10.1063/5.0270431)

◇ Morales, Carlos, et al. "Stabilization of Ce³⁺ cations via U–Ce charge transfer in mixed oxides: consequences on the thermochemical water splitting to hydrogen." *Journal of Physics: Energy* 7.2 (2025): 025012.

DOI: [10.1088/2515-7655/adbad9](https://doi.org/10.1088/2515-7655/adbad9)

◇ **Baunthiyal, Aman**, et al. "Sputter-Deposited -GaO Films With Al Top Electrodes for Resistive Random Access Memory Technology." 2023 IEEE Nanotechnology Materials and Devices Conference (NMDC). IEEE, 2023.

DOI: [10.1109/NMDC57951.2023.10343972](https://doi.org/10.1109/NMDC57951.2023.10343972)

◇ **Baunthiyal, Aman**, et al. "Growth and characterization of sputter-deposited Ga₂O₃-based memristive devices." *Applied Physics Letters* 123.21 (2023).

DOI: [10.1063/5.0170354](https://doi.org/10.1063/5.0170354)

SOFTWARE SKILLS

- Origin Pro
- C++
- LabVIEW
- Python
- Casaxps
- LaTeX

SOFT SKILLS

- Good communication skills
- Analytical Thinking
- Problem-Solving
- Adaptability
- Teamwork
- Time Management
- Curiosity and Creativity
- Ethical Awareness

TECHNICAL SKILLS

- ◇ Physical vapor deposition (PVD) techniques
- ◇ Grazing Incidence XRD at Petra III, Desy
- ◇ Scanning Tunneling Microscopy (STM)
- ◇ X-ray diffraction (XRD)
- ◇ Bruker Conductive Atomic Force Microscope (C/AFM)
- ◇ Scanning Electron Microscopy (SEM)
- ◇ X-ray Photo-electron Spectroscopy (XPS)
- ◇ Auger electron spectroscopy (AES)
- ◇ Low Energy Electron Microscopy/Diffraction (LEED)

TALKS AND CONFERENCES

Presented research on structural and electrical properties of Ga_2O_3 films at various conferences and invited talks:

- ◇ IEEE Nanotechnology Materials and Devices Conference, Italy 2023
- ◇ 36th European Conference on Surface Science, Poland 2023
- ◇ International Union of Materials Research Society, IIT Jodhpur, India 2022
- ◇ DPG-Frühjahrstagung, Regensburg, Germany 2022
- ◇ Institute of Solid State Physics Workshop, University of Bremen, Riezlern, Austria 2022
- ◇ Invited Talk in Prof. Subhashinsh Gangopadhyay group, BITS Pilani, Pilani, India 2024
- ◇ Invited Talk in Prof. Jan Ingo Flege group, BTU Cottbus, Germany 2025

INTERNSHIPS AND SCHOOLS

INTERN, IIT JODHPUR, INDIA **October, 2019**

◇ Project title: *Morphological study of Organic thin films using low-temperature STM.*

GUEST RESEARCHER, UNIVERSITY OF BREMEN **March, 2019**

◇ Project title: *Morphological study of VO_2 thin films on the different substrate using variable temperature STM.*

Aman Baunthiyal, MAPEX, University of Bremen

MATRAC₁ SCHOOL SYNCHROTRON VISIT, HELMHOLTZ-ZENTRUM HEREON, HAMBURG **March, 2019**

◇ Aim: *Practical training on various techniques at Petra III, Desy, Germany and MAX IV, Lund, Sweden.*

AWARDS AND ACHIEVEMENT

- ◇ Indian Institute of Technology - Joint Admission test for Masters (IIT-JAM), Qualified with All India Rank (AIR) 426 out of app. 12000 candidates.
- ◇ MAPEX Center for Materials and Processes internship grant, University of Bremen, For carrying out an internship at University of Bremen.
- ◇ Postgraduate International Program travel grant, University of Bremen, For various all national and international conferences.